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SCES617A-OCTOBER 2004-REVISED APRIL 2008

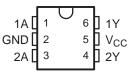
# DUAL INVERTER BUFFER/DRIVER WITH OPEN-DRAIN OUTPUTS

#### **FEATURES**

- Qualified for Automotive Applications
- Supports 5-V V<sub>CC</sub> Operation
- Max t<sub>pd</sub> of 3.4 ns at 3.3 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Inputs and Open-Drain Outputs Accept Voltages up to 5.5 V
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

# DBV OR DCK PACKAGE (TOP VIEW)



### **DESCRIPTION/ORDERING INFORMATION**

This dual inverter buffer/driver is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The output of the SN74LVC2G06-Q1 device is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32 mA.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION(1)

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING (3)
-40°C to 125°C	SOT (SOT-23) – DBV	Tape and reel	SN74LVC2G06QDBVRQ1	C06_
-40°C to 125°C	SOT (SC-70) - DCK	Tape and reel	SN74LVC2G06QDCKRQ1	CT_

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

# FUNCTION TABLE (EACH INVERTER)

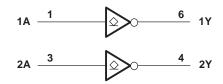
INPUT A	OUTPUT Y
Н	L
L	Н



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### **LOGIC DIAGRAM (POSITIVE LOGIC)**



# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-impedal	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high or low s	-0.5	6.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
0	Dackage thermal impedance (4)	DBV package		165	°C/W
$\theta_{JA}$	Package thermal impedance (4)	DCK package		259	C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The value of  $V_{CC}$  is provided in the recommended operating conditions table.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

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# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT	
\/	Cumply voltage	Operating	1.65	5.5	V	
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
.,	High level input valtage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V	
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	2		V	
		V <sub>CC</sub> = 4.5 V to 5.5 V	$0.7 \times V_{CC}$			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Low level input valters	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		V		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		0.8	V	
		V <sub>CC</sub> = 4.5 V to 5.5 V		$0.3 \times V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	5.5	V	
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8		
I <sub>OL</sub>	Low-level output current	V 2.V		16	mA	
		V <sub>CC</sub> = 3 V		24		
		V <sub>CC</sub> = 4.5 V		32		
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$		20		
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		$V_{CC} = 5 V \pm 0.5 V$		5		
T <sub>A</sub>	Operating free-air temperature		-40	125	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMET	ΓER	TEST C	CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup> MAX	UNIT		
		I <sub>OL</sub> = 100 μA		1.65 V to 5.5 V	0.1			
		I <sub>OL</sub> = 4 mA		1.65 V	0.45			
		I <sub>OL</sub> = 8 mA		2.3 V	0.3			
		Ι 40 Δ	$T_A = -40^{\circ}C$ to $85^{\circ}C$	2.1/	0.4			
$V_{OL} = 16 i$ $I_{OL} = 24 i$		I <sub>OL</sub> = 16 mA	T <sub>A</sub> = 125°C	3 V	0.45	V		
		1 04 m A	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$	3 V	0.55			
		I <sub>OL</sub> = 24 mA	T <sub>A</sub> = 125°C	3 V	0.65			
		1 20 m A	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$	4.5.\/	0.55			
		$I_{OL} = 32 \text{ mA}$	T <sub>A</sub> = 125°C	4.5 V	0.65	5		
I <sub>I</sub> A ir	nputs	V <sub>I</sub> = 5.5 V or GND		0 to 5.5 V	±5	μΑ		
I <sub>off</sub>		$V_I$ or $V_O = 5.5 \text{ V}$		0	±10	μΑ		
I <sub>CC</sub>		$V_I = 5.5 \text{ V or GND},$	I <sub>O</sub> = 0	1.65 V to 5.5 V	10	μΑ		
$\Delta I_{CC}$		One input at V <sub>CC</sub> – 0.6 V,	Other inputs at V <sub>CC</sub> or GND	3 V to 5.5 V	500	μΑ		
Ci		V <sub>I</sub> = V <sub>CC</sub> or GND		3.3 V	3.5	pF		

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.



# **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
	(INFOT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	Α	Y	1.8	7.2	1	3.9	1	3.4	1	2.9	ns

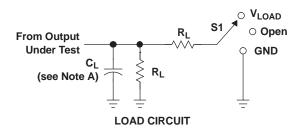
# **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 \text{ V}$	$V_{CC} = 3.3 \text{ V}$	$V_{CC} = 5 V$	UNIT
		TEST CONDITIONS	TYP	TYP	TYP	TYP	UNII
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	2	2	3	4	pF

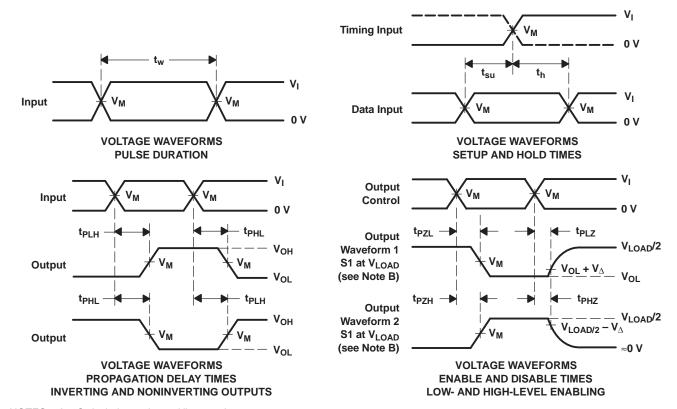


# PARAMETER MEASUREMENT INFORMATION (OPEN DRAIN)



TEST	<b>S1</b>
t <sub>PZL</sub> (see Notes E and F)	V <sub>LOAD</sub>
t <sub>PLZ</sub> (see Notes E and G)	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	$V_{LOAD}$

	INPU						
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	$R_L$	$oldsymbol{V}_{\Delta}$
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤ <b>2 ns</b>	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤ <b>2 ns</b>	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 $\Omega$	0.15 V
3.3 V $\pm$ 0.3 V	3 V	≤ <b>2.5</b> ns	1.5 V	6 V	50 pF	500 $\Omega$	0.3 V
5 V $\pm$ 0.5 V	V <sub>CC</sub>	≤ <b>2.5</b> ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	50 pF	500 $\Omega$	0.3 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. Since this device has open-drain outputs,  $t_{PLZ}$  and  $t_{PZL}$  are the same as  $t_{pd}$ .
- F.  $t_{PZL}$  is measured at  $V_M$ .
- G.  $t_{PLZ}$  is measured at  $V_{OL} + V_{\Delta}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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## PACKAGE OPTION ADDENDUM



10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVC2G06QDCKRQ1	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	СТО	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC2G06-Q1:



# **PACKAGE OPTION ADDENDUM**

10-Dec-2020

● Catalog: SN74LVC2G06

● Enhanced Product: SN74LVC2G06-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G06QDCKRQ1	SC70	DCK	6	3000	179.0	8.4	2.2	2.5	1.2	4.0	8.0	Q3

# **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G06QDCKRQ1	SC70	DCK	6	3000	203.0	203.0	35.0



SMALL OUTLINE TRANSISTOR



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

  4. Falls within JEDEC MO-203 variation AB.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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